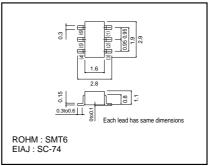
# Power management(dual digital transistors) IMD16A

#### Features

- 1) Two digital class transistors in a SMT package.
- 2) Up to 500mA can be driven.
- 3) Low V<sub>CE(sat)</sub> of drive transistors for low power dissipation.

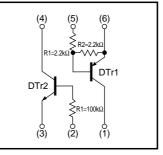
## •External dimensions (Unit : mm)



#### •Package, marking, and packaging specifications

Part No.	IMD16A
Package	SMT6
Marking	D16
Code	T108
Basic ordering unit (pieces)	3000

## Equivalent circuit



# •Absolute maximum ratings (Ta=25°C)

DTr1 (PNP)

Parameter	Symbol	Limits	Unit
Supply voltage	Vcc	-50	V
Input voltage	Vin	-12	V
	V III	5	
Output current	lc	-500	mA

#### DTr<sub>2</sub> (NPN)

Parameter	Symbol	Limits	Unit
Collector-base voltage	Vсво	50	V
Collector-emitter voltage	Vceo	50	V
Emitter-base voltage	Vebo	5	V
Collector current	lc	100	mA

#### Total

Parameter	Symbol	Limits	Unit
Collector power dissipation	Pd	300(TOTAL)	mW *
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

\* 200mW per element must not be exceeded.



# Transistors

# ●Electrical characteristics (Ta=25°C)

## DTr<sub>1</sub>

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
	VI(off)	-	-	-0.3	v	Vcc= –5V , Io= –100μA
Input voltage	VI(on) -2 V		Vo= -0.3V , Io= -20mA			
Output voltage	VO(on)	-	-	-0.3	V	Io/II= -50mA / -2.5mA
Input current	h	_	-	-3	mA	VI= -5V
Output current	IO(off)	-	-	-0.5	μΑ	Vcc= −50V , V⊨0V
DC current gain	Gi	82	-	-	-	Io= -50mA , Vo= -5V *1
Transition frequency	fт	-	250	-	MHz	Vc= –10V , I=50mA , f=100MHz *2
Input resistance	R1	1.54	2.2	2.86	kΩ	-
Resistance ratio	R2/R1	0.8	1.0	1.2	-	-

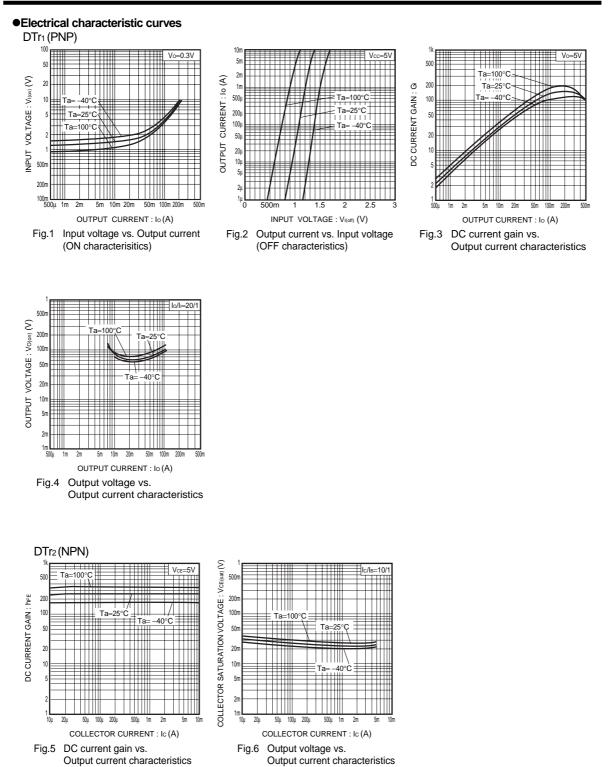
\*1 Measured using pulse current. \*2 Transition frequency of mounted transistor.

DTr<sub>2</sub>

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	ВУсво	50	-	-	V	Ic=50μA
Collector-emitter breakdown voltage	BVCEO	50	-	-	V	Ic=1mA
Emitter-base breakdown voltage	ВVево	5	-	-	V	Ιε=50μΑ
Collector cutoff current	Ісво	_	-	0.5	μA	Vcb=50V
Emitter cutoff current	Іево	-	-	0.5	μA	VEB=4V
Collector-emitter saturation voltage	VCE(sat)	-	-	0.3	V	Ic/IB=1mA/0.1mA
DC current transfer ratio	hfe	100	250	600	-	Vce=5V , Ic=1mA
Transition frequency	f⊤	-	250	-	MHz	Vce=10V , Ie=-5mA , f=100MHz *
Input resistance	R1	70	100	130	kΩ	_

\*Transition frequency of mounted transistor.

## Transistors



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3/3

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